

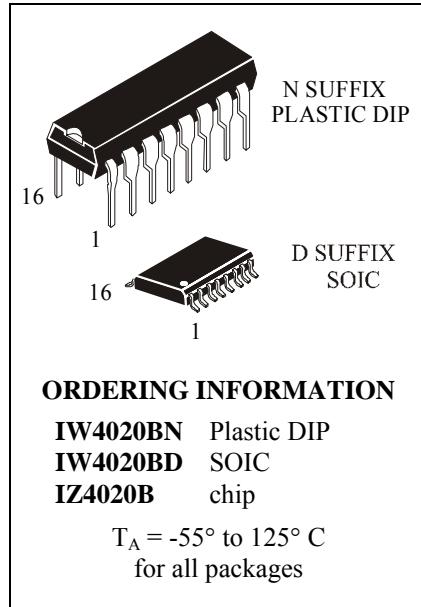
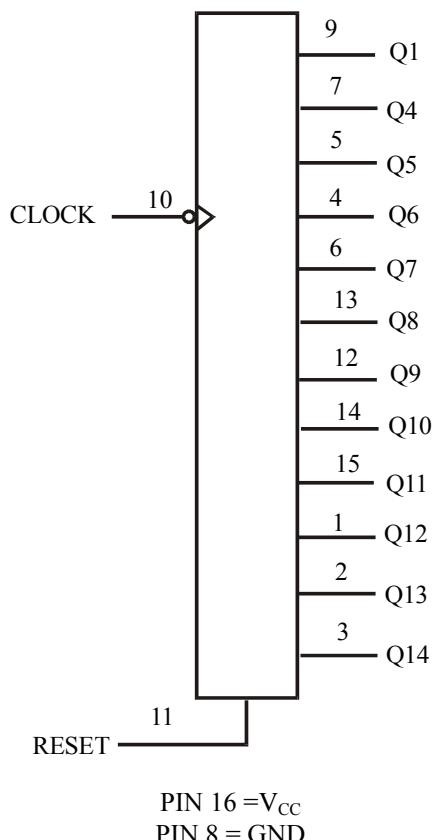
IW4020B

14 Stage Ripple-Carry Binary Counter/Divider High-Voltage Silicon-Gate CMOS

The IW4020B is ripple-carry binary counter. All counter stages are master-slave flip-flops. The state of a counter advances one count on the negative transition of each input pulse; a high level on the RESET line resets the counter to its all zeros state. Schmitt trigger action on the input-pulse line permits unlimited rise and fall times.

- Operating Voltage Range: 3.0 to 18 V
- Maximum input current of 1 μ A at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (over full package temperature range):

1.0 V min @ 5.0 V supply
2.0 V min @ 10.0 V supply
2.5 V min @ 15.0 V supply

LOGIC DIAGRAM**PIN ASSIGNMENT**

Q12	1 ●	16	V _{CC}
Q13	2	15	Q11
Q14	3	14	Q10
Q6	4	13	Q8
Q5	5	12	Q9
Q7	6	11	RESET
Q4	7	10	CLOCK
GND	8	9	Q1

FUNCTION TABLE

Inputs		Output
Clock	Reset	Output state
	L	No change
	L	Advance to next state
X	H	All Outputs are low

H= high level

L = low level

X=don't care



INTEGRAL

MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage (Referenced to GND)	-0.5 to +20	V
V _{IN}	DC Input Voltage (Referenced to GND)	-0.5 to V _{CC} +0.5	V
V _{OUT}	DC Output Voltage (Referenced to GND)	-0.5 to V _{CC} +0.5	V
I _{IN}	DC Input Current, per Pin	±10	mA
P _D	Power Dissipation in Still Air, Plastic DIP+ SOIC Package+	500* ¹	mW
P _{tot}	Power Dissipation per Output Transistor	100	mW
T _{stg}	Storage Temperature	-65 to +150	°C
T _L	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package)	260	°C

*Maximum Ratings are those values beyond which damage to the device may occur.

Functional operation should be restricted to the Recommended Operating Conditions.

*¹ For T_A=-55 to 100°C (package plastic DIP), for T_A=-55 to 65°C (package SOIC)

+Derating - Plastic DIP: - 12 mW/°C from 100°C to 125°C

SOIC Package: : - 7 mW/°C from 65°C to 125°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	DC Supply Voltage (Referenced to GND)	3.0	18	V
V _{IN} , V _{OUT}	DC Input Voltage, Output Voltage (Referenced to GND)	0	V _{CC}	V
T _A	Operating Temperature, All Package Types	-55	+125	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{IN} and V_{OUT} should be constrained to the range GND≤(V_{IN} or V_{OUT})≤V_{CC}.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.



DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

Symbol	Parameter	Test Conditions	V _{CC} V	Guaranteed Limit			Unit
				-55°C	25°C	125°C	
V _{IH}	Minimum High-Level Input Voltage	V _{OUT} =0.5 V or V _{CC} - 0.5 V V _{OUT} =1.0 V or V _{CC} - 1.0 V V _{OUT} =1.5 V or V _{CC} - 1.5 V	5.0 10 15	3.5 7.0 11.0	3.5 7.0 11.0	3.5 7.0 11.0	V
V _{IL}	Maximum Low -Level Input Voltage	V _{OUT} =0.5 V or V _{CC} - 0.5 V V _{OUT} =1.0 V or V _{CC} - 1.0 V V _{OUT} =1.5 V or V _{CC} - 1.5 V	5.0 10 15	1.5 3.0 4.0	1.5 3.0 4.0	1.5 3.0 4.0	V
V _{OH}	Minimum High-Level Output Voltage	V _{IN} = GND or V _{CC}	5.0 10 15	4.95 9.95 14.95	4.95 9.95 14.95	4.95 9.95 14.95	V
V _{OL}	Maximum Low-Level Output Voltage	V _{IN} = GND or V _{CC}	5.0 10 15	0.05 0.05 0.05	0.05 0.05 0.05	0.05 0.05 0.05	V
I _{IN}	Maximum Input Leakage Current	V _{IN} = GND or V _{CC}	18	±0.1	±0.1	±1.0	µA
I _{CC}	Maximum Quiescent Supply Current (per Package)	V _{IN} = GND or V _{CC}	5.0 10 15 20	5 10 20 100	5 10 20 100	150 300 600 3000	µA
I _{OL}	Minimum Output Low (Sink) Current	V _{IN} = GND or V _{CC} U _{OL} =0.4 V U _{OL} =0.5 V U _{OL} =1.5 V	5.0 10 15	0.64 1.6 4.2	0.51 1.3 3.4	0.36 0.9 2.4	mA
I _{OH}	Minimum Output High (Source) Current	V _{IN} = GND or V _{CC} U _{OH} =2.5 V U _{OH} =4.6 V U _{OH} =9.5 V U _{OH} =13.5 V	5.0 5.0 10 15	-2.0 -0.64 -1.6 -4.2	-1.6 -0.51 -1.3 -3.4	-1.15 -0.36 -0.9 -2.4	mA

AC ELECTRICAL CHARACTERISTICS ($C_L=50\text{ pF}$, $R_L=200\text{ k}\Omega$, $t_r=t_f=20\text{ ns}$)

Symbol	Parameter	V_{CC} V	Guaranteed Limit			Unit
			-55°C	25°C	125°C	
f_{max}	Maximum Clock Frequency (Figure 1)	5.0 10 15		3.5 8 12		MHz
t_{PLH}, t_{PHL}	Maximum Propagation Delay, Clock to Q1 (Figure 1)	5.0 10 15	720 320 260	360 160 130	720 320 260	ns
t_{PLH}, t_{PHL}	Maximum Propagation Delay, Q_n to Q_{n+1} (Figure 2)	5.0 10 15	660 160 120	330 80 60	660 160 120	ns
t_{PHL}	Maximum Propagation Delay, Reset to Any Q (Figure 3)	5.0 10 15	560 240 200	280 120 100	560 240 200	ns
t_{TLH}, t_{THL}	Maximum Output Transition Time, Any Output (Figure 1)	5.0 10 15	400 200 160	200 100 80	400 200 160	ns
C_{IN}	Maximum Input Capacitance	-		7.5		pF

TIMING REQUIREMENTS ($C_L=50\text{ pF}$, $R_L=200\text{ k}\Omega$, $t_r=t_f=20\text{ ns}$)

Symbol	Parameter	V_{CC} V	Guaranteed Limit			Unit
			-55°C	25°C	125°C	
t_w	Minimum Pulse Width, Clock (Figure 1)	5.0 10 15	280 120 80	140 60 40	280 120 80	ns
t_w	Minimum Pulse Width, Reset (Figure 3)	5.0 10 15	400 160 120	200 80 60	400 160 120	ns
t_{rem}	Minimum Removal Time, Reset(Figure 3)	5.0 10 15	700 300 200	350 150 100	700 300 200	ns
t_r, t_f	Maximum Input Rise and Fall Times, Clock (Figure 1)	5.0 10 15		Unlimited		ns

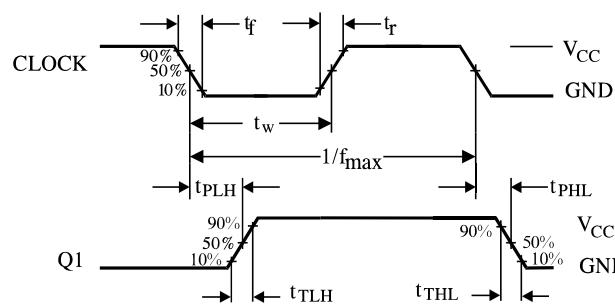


Figure 1. Switching Waveforms

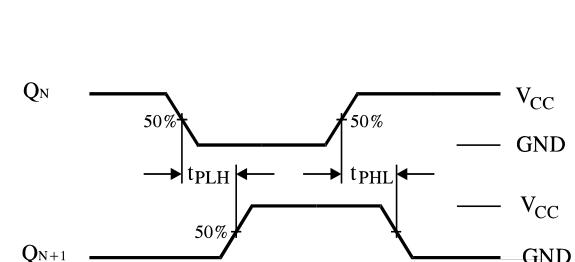


Figure 2. Switching Waveforms

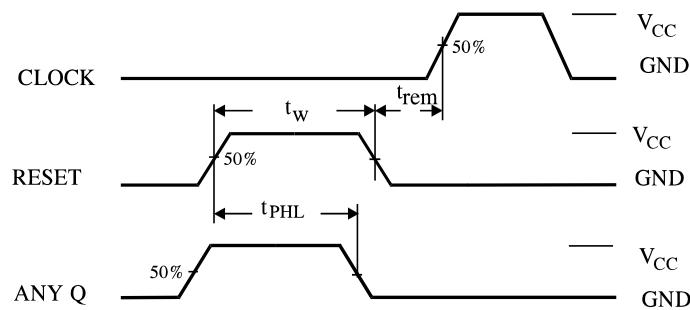
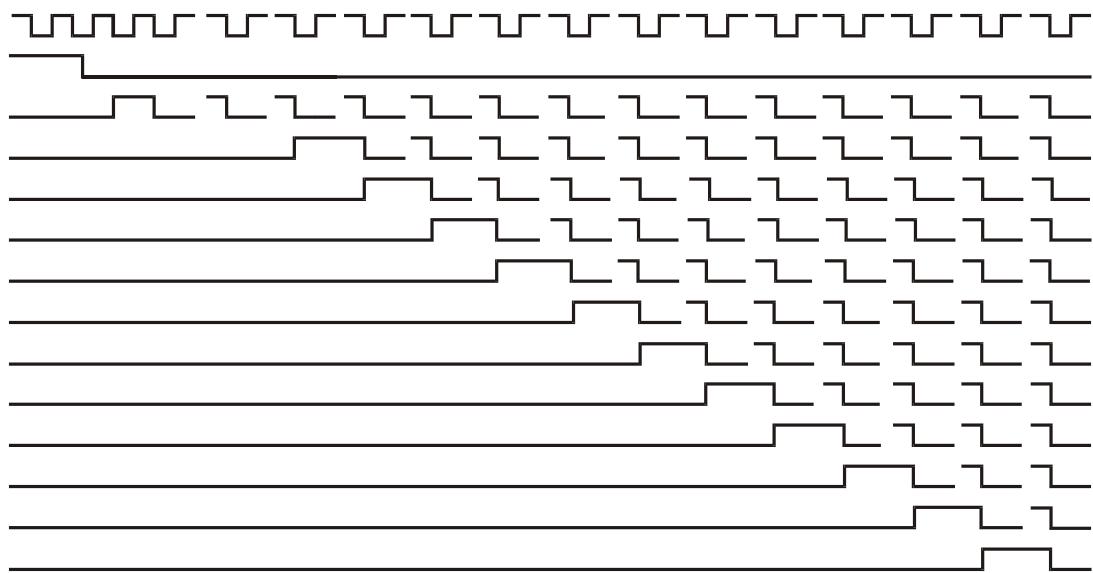
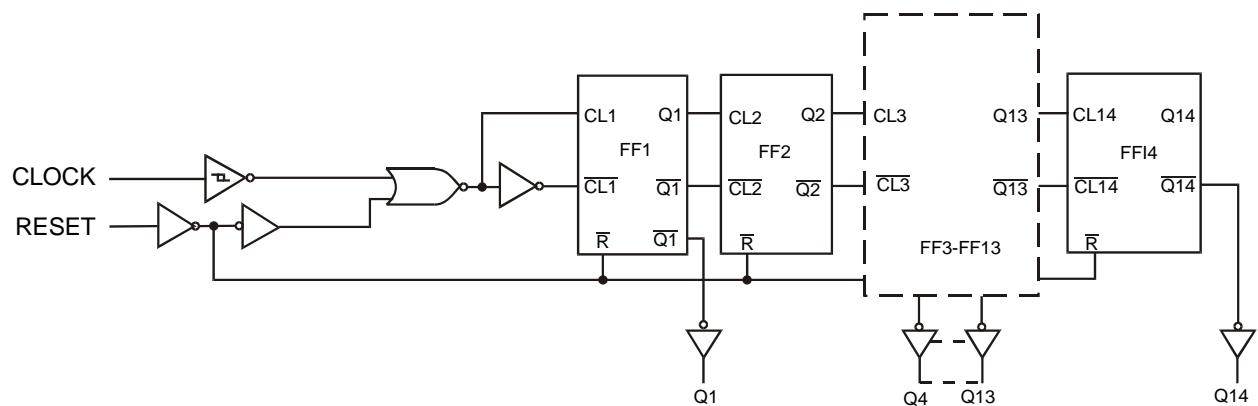
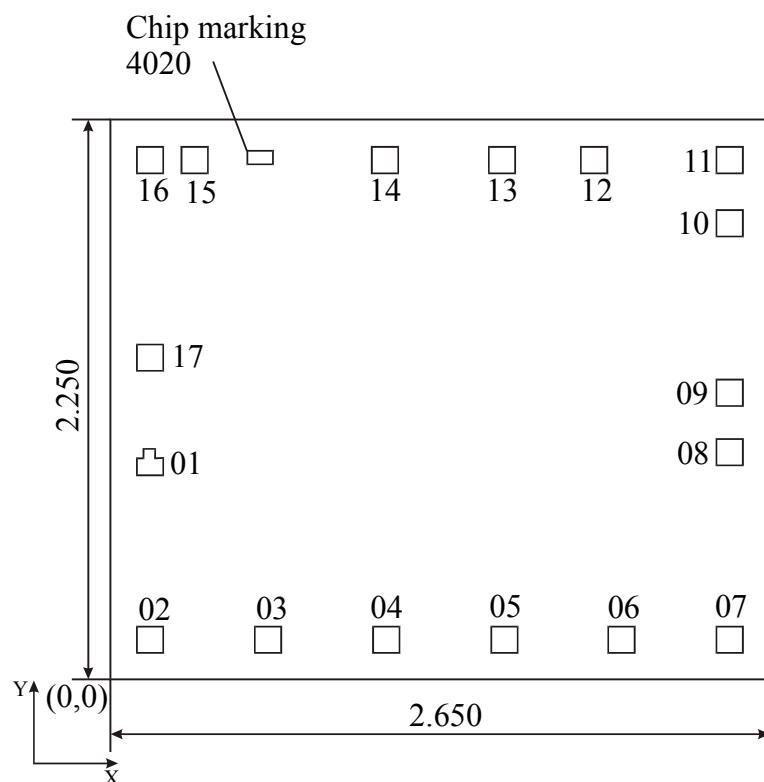


Figure 3. Switching Waveforms

TIMING DIAGRAM**EXPANDED LOGIC DIAGRAM**

CHIP PAD DIAGRAM

Location of marking (mm): left lower corner x=0.550, y=2.070.

Chip thickness: 0.46 ± 0.02 mm.

PAD LOCATION

Pad No	Symbol	Location (left lower corner), mm		Pad size, mm
		X	Y	
01	Q12	0.106	0.820	0.106 x 0.106
02	Q13	0.106	0.106	0.106 x 0.106
03	Q14	0.580	0.106	0.106 x 0.106
04	Q6	1.055	0.106	0.106 x 0.106
05	Q5	1.530	0.106	0.106 x 0.106
06	Q7	2.000	0.106	0.106 x 0.106
07	Q4	2.435	0.106	0.106 x 0.106
08	GND	2.435	0.860	0.106 x 0.106
09	Q1	2.435	1.100	0.106 x 0.106
10	CLOCK	2.435	1.780	0.106 x 0.106
11	-	2.435	2.034	0.106 x 0.106
12	RESET	1.890	2.034	0.106 x 0.106
13	Q9	1.520	2.034	0.106 x 0.106
14	Q8	1.050	2.034	0.106 x 0.106
15	Q10	0.285	2.034	0.106 x 0.106
16	Q11	0.106	2.034	0.106 x 0.106
17	V _{CC}	0.106	1.240	0.106 x 0.106

Note: Pad location and size is given as per passivation layer

